



**THE DATASHEET OF  
ZXMN6A08KTC**



### Product Summary

$V_{(BR)DSS}$	$R_{DS(on)}$	$I_D$ $T_A = 25^\circ C$
60V	80m $\Omega$ @ $V_{GS} = 10V$	7.90A
	150m $\Omega$ @ $V_{GS} = 4.5V$	5.75A

### Description and Applications

This new generation MOSFET has been designed to minimize the on-state resistance ( $R_{DS(on)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- DC-DC Converters
- Power management functions

### Features and Benefits

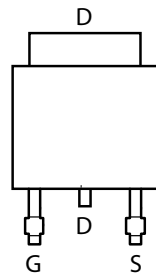
- Low on-resistance
- Fast switching speed
- "Green" component and RoHS compliant (Note 1)

### Mechanical Data

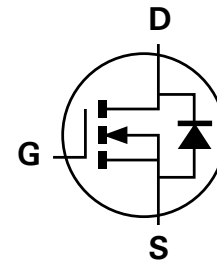
- Case: TO-252
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0 (Note 1)
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals Connections: See Diagram
- Terminals: Matte Tin Finish annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.33 grams (approximate)



TOP VIEW



PIN OUT -TOP VIEW



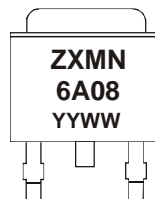
Equivalent Circuit

### Ordering Information (Note 1)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXMN6A08KTC	See Below	13	16	2,500

Note: 1. Diodes, Inc. defines "Green" products as those which are Eu RoHS compliant and contain no halogens or antimony compounds; further information about Diodes Inc.'s "Green" Policy can be found on our website. For packaging details, go to our website.

### Marking Information



ZXMN = Product Type Marking Code, Line 1  
 6A08 = Product Type Marking Code, Line 2  
 YYWW = Date Code Marking  
 YY = Year (ex: 09 = 2009)  
 WW = Week (01-52)

**Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

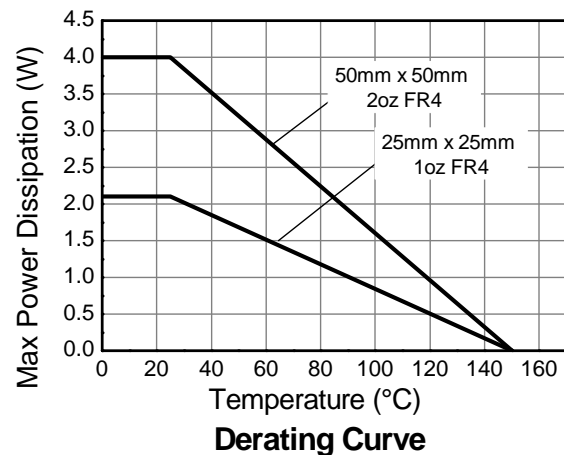
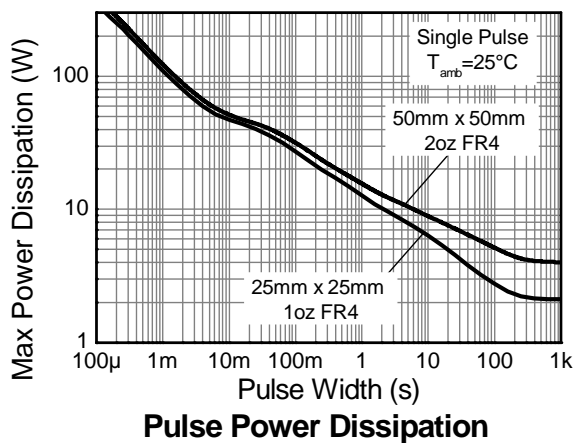
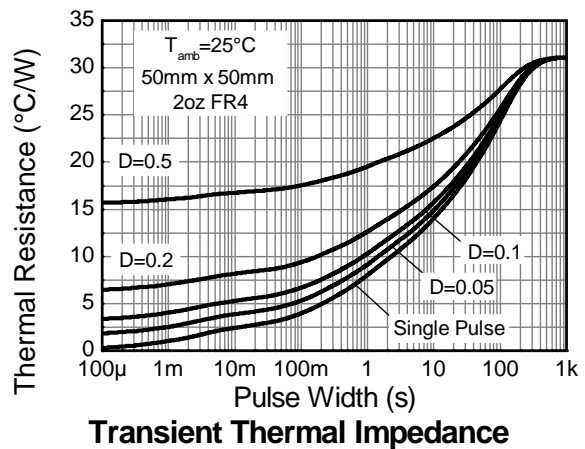
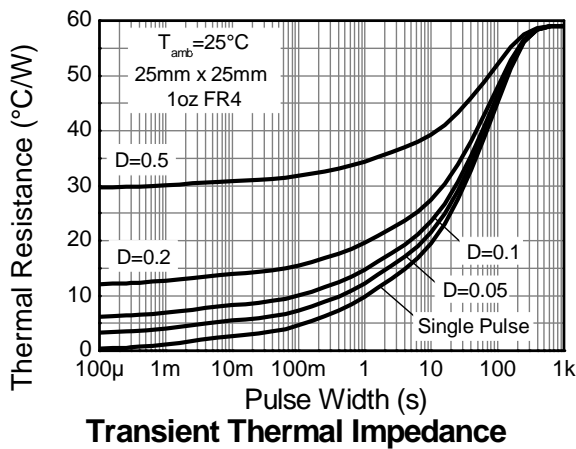
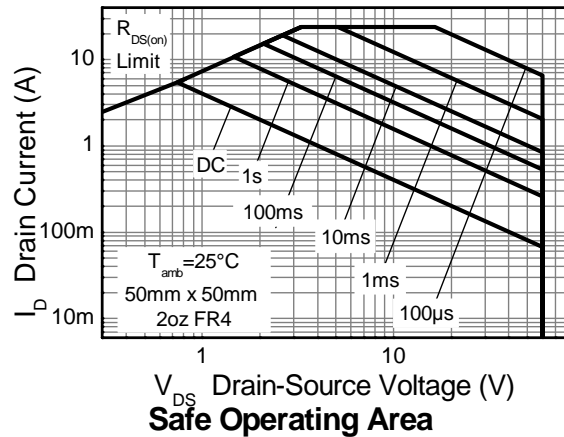
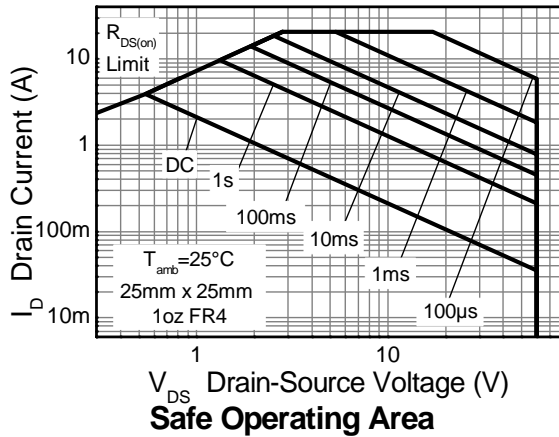
Characteristic		Symbol	Value	Unit	
Drain-Source voltage		V <sub>DSS</sub>	60	V	
Gate-Source voltage		V <sub>GS</sub>	±20	V	
Continuous Drain current	V <sub>GS</sub> = 10V	(Note 3)	7.90	A	
		T <sub>A</sub> =70°C (Note 3)	6.30		
		(Note 2)	5.36		
Pulsed Drain current	V <sub>GS</sub> = 10V	(Note 4)	I <sub>DM</sub>	24.3	A
Continuous Source current (Body diode)		(Note 3)	I <sub>S</sub>	9.0	A
Pulsed Source current (Body diode)		(Note 4)	I <sub>SM</sub>	24.3	A

**Thermal Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Power dissipation Linear derating factor	(Note 2)	P <sub>D</sub>	4.13	W mW/°C
			33.0	
	(Note 3)		8.94	
			71.5	
Thermal Resistance, Junction to Ambient	(Note 5)	R <sub>θJA</sub>	2.12	°C/W
			16.9	
	(Note 2)		30.3	
	(Note 3)		14.0	
Thermal Resistance, Junction to Lead	(Note 5)	R <sub>θJL</sub>	59.1	°C/W
	(Note 6)		2.77	
Operating and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-55 to 150	°C

- Notes:
2. For a device surface mounted on 50mm x 50mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
  3. Same as note 2, except the device is measured at t ≤ 10 sec.
  4. Same as note 2, except the device is pulsed with D = 0.02 and pulse width 300 μs. The pulse current is limited by the maximum junction temperature.
  5. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
  6. Thermal resistance from junction to solder-point (at the end of the drain lead).

**Thermal Characteristics**

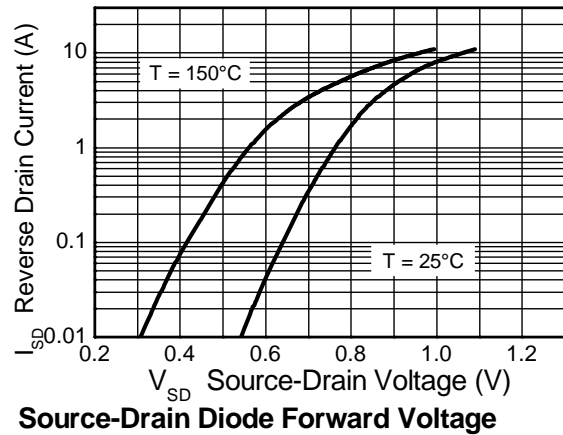
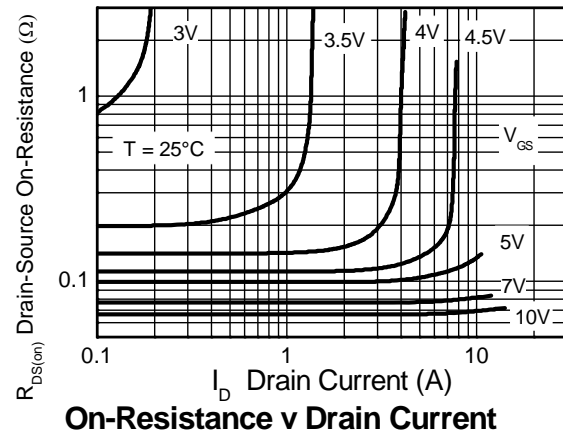
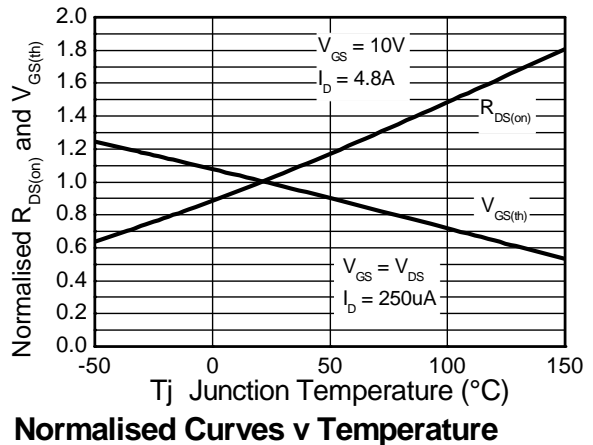
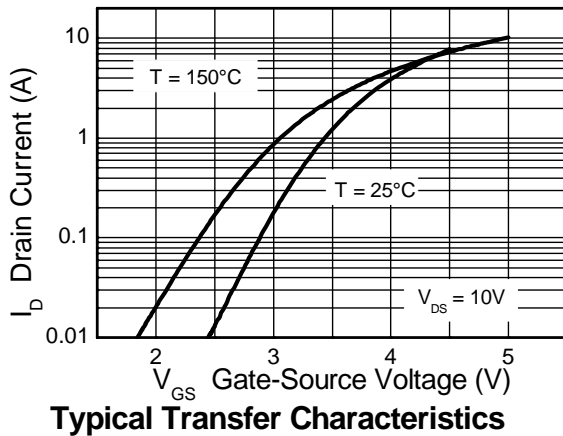
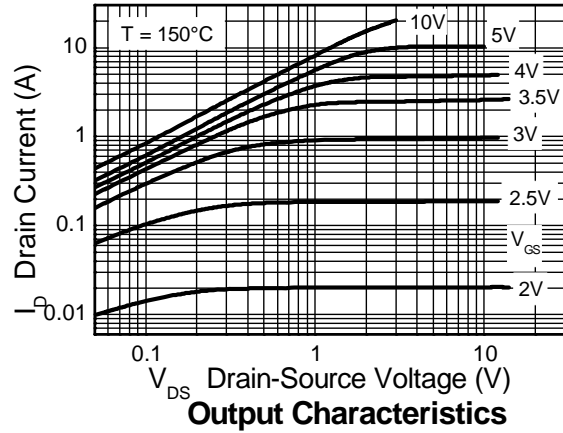
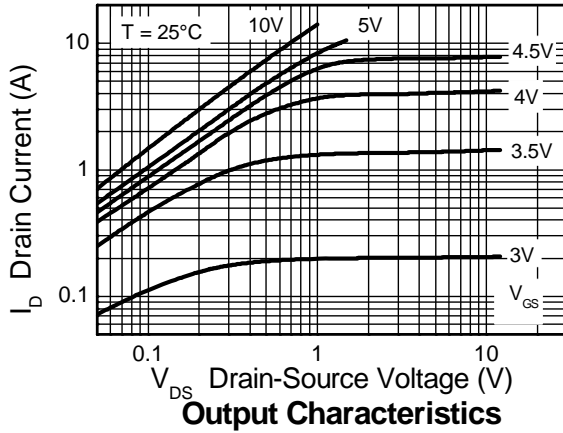


**Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

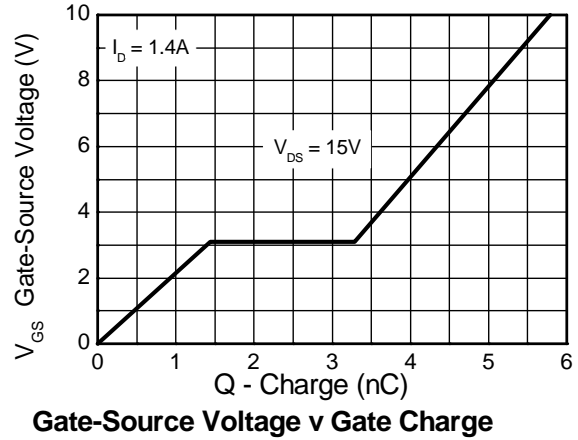
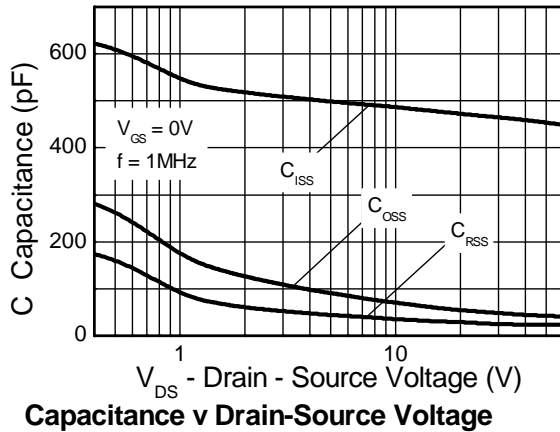
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	—	—	V	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	—	0.5	μA	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	—	—	±100	nA	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	V <sub>GS(th)</sub>	1.0	—	3.0	V	I <sub>D</sub> = 250μA, V <sub>DS</sub> = V <sub>GS</sub>
Static Drain-Source On-Resistance (Note 7)	R <sub>DS(on)</sub>	—	—	0.080	Ω	V <sub>GS</sub> = 10V, I <sub>D</sub> = 4.8A
				0.150		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 4.2A
Forward Transconductance (Notes 7 & 8)	g <sub>fs</sub>	—	6.6	—	S	V <sub>DS</sub> = 15V, I <sub>D</sub> = 4.8A
Diode Forward Voltage (Note 7)	V <sub>SD</sub>	—	0.88	0.95	V	I <sub>S</sub> = 4.0A, V <sub>GS</sub> = 0V
Reverse recovery time (Note 8)	t <sub>rr</sub>	—	19.2	—	ns	I <sub>S</sub> = 1.4A, di/dt = 100A/μs
Reverse recovery charge (Note 8)	Q <sub>rr</sub>	—	30.3	—	nC	
<b>DYNAMIC CHARACTERISTICS (Note 8)</b>						
Input Capacitance	C <sub>iSS</sub>	—	459	—	pF	V <sub>DS</sub> = 40V, V <sub>GS</sub> = 0V f = 1MHz
Output Capacitance	C <sub>oss</sub>	—	44.2	—	pF	
Reverse Transfer Capacitance	C <sub>rSS</sub>	—	24.1	—	pF	
Total Gate Charge	Q <sub>g</sub>	—	3.8	—	nC	V <sub>GS</sub> = 4.5V
Total Gate Charge	Q <sub>g</sub>	—	5.8	—	nC	V <sub>GS</sub> = 10V
Gate-Source Charge	Q <sub>gs</sub>	—	1.4	—	nC	
Gate-Drain Charge	Q <sub>gd</sub>	—	1.9	—	nC	
Turn-On Delay Time (Note 9)	t <sub>D(on)</sub>	—	2.6	—	ns	V <sub>DD</sub> = 30V, V <sub>GS</sub> = 10V I <sub>D</sub> = 1.5A, R <sub>G</sub> ≅ 6.0Ω
Turn-On Rise Time (Note 9)	t <sub>r</sub>	—	2.1	—	ns	
Turn-Off Delay Time (Note 9)	t <sub>D(off)</sub>	—	12.3	—	ns	
Turn-Off Fall Time (Note 9)	t <sub>f</sub>	—	4.6	—	ns	

- Notes:
7. Measured under pulsed conditions. Pulse width ≤ 300μs; duty cycle ≤ 2%
  8. For design aid only, not subject to production testing.
  9. Switching characteristics are independent of operating junction temperatures.

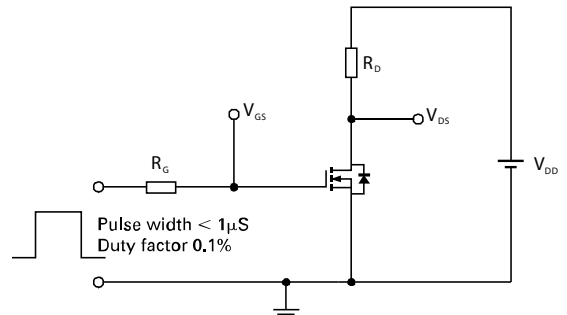
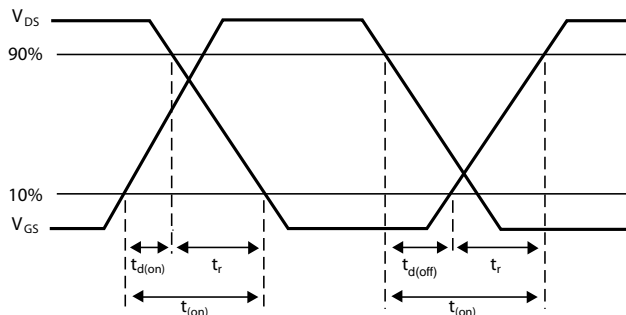
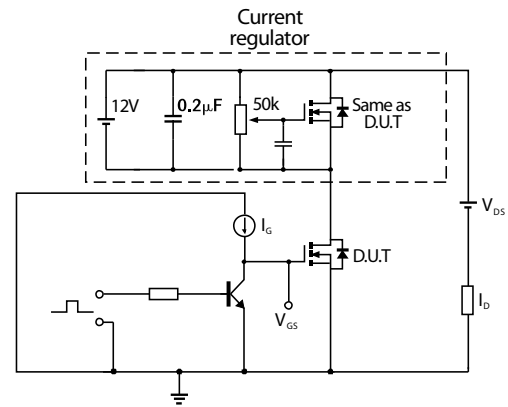
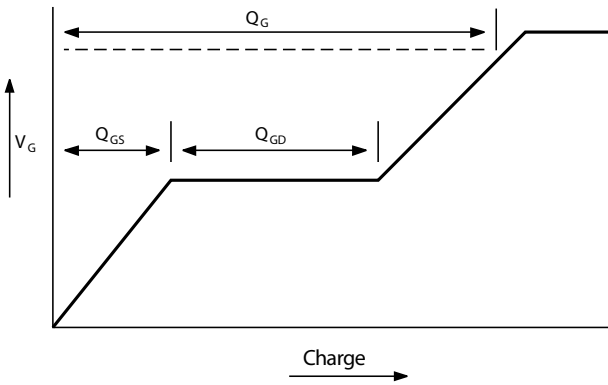
**Typical Characteristics**



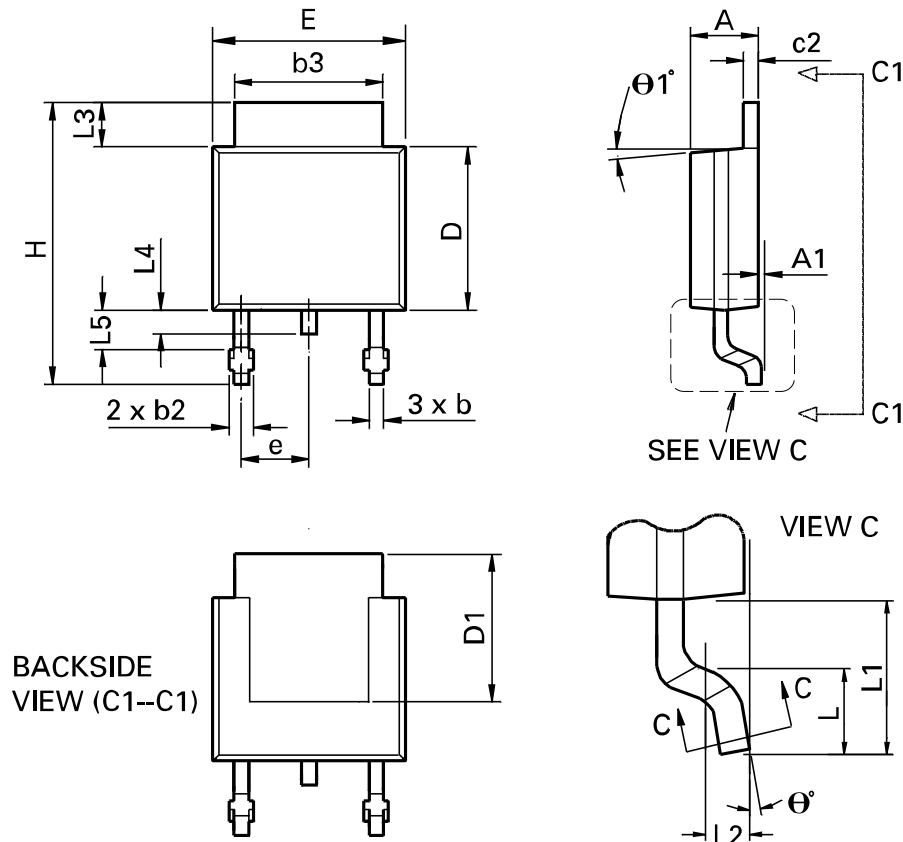
**Typical Characteristics - continued**



**Test Circuits**

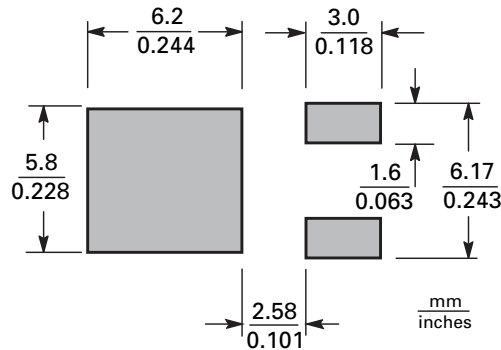


**Package Outline Dimensions**



DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min	Max	Min	Max		Min	Max	Min	Max
<b>A</b>	0.086	0.094	2.18	2.39	<b>e</b>	0.090 BSC		2.29 BSC	
<b>A1</b>	-	0.005	-	0.127	<b>H</b>	0.370	0.410	9.40	10.41
<b>b</b>	0.020	0.035	0.508	0.89	<b>L</b>	0.055	0.070	1.40	1.78
<b>b2</b>	0.030	0.045	0.762	1.14	<b>L1</b>	0.108 REF		2.74 REF	
<b>b3</b>	0.205	0.215	5.21	5.46	<b>L2</b>	0.020 BSC		0.508 BSC	
<b>c</b>	0.018	0.024	0.457	0.61	<b>L3</b>	0.035	0.065	0.89	1.65
<b>c2</b>	0.018	0.023	0.457	0.584	<b>L4</b>	0.025	0.040	0.635	1.016
<b>D</b>	0.213	0.245	5.41	6.22	<b>L5</b>	0.045	0.060	1.14	1.52
<b>D1</b>	0.205	-	5.21	-	<b><math>\theta1^\circ</math></b>	0°	10°	0°	10°
<b>E</b>	0.250	0.265	6.35	6.73	<b><math>\theta^\circ</math></b>	0°	15°	0°	15°
<b>E1</b>	0.170	-	4.32	-	-	-	-	-	-

## Suggested Pad Layout



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